Jameco Part number 53090

8755A/8755A-2
16,384-BIT EPROM WITH I/O

- **2048 Words x 8 Bits**
- **Single + 5V Power Supply (V_{cc})**
- **Directly Compatible with 8085A and 8088 Microprocessors**
- **U.V. Erasable and Electrically Reprogrammable**
- **Internal Address Latch**
- **2 General Purpose 8-Bit I/O Port**
- **Each I/O Port Line Individually Programmable as Input or Output**
- **Multiplexed Address and Data Bus**
- **40-Pin DIP**
- **Available in EXPRESS**
  - **Standard Temperature Range**
  - **Extended Temperature Range**

The Intel(R) 8755A is an erasable and electrically reprogrammable ROM (EPROM) and I/O chip to be used in the 8085A and iAPX 88 microprocessor systems. The EPROM portion is organized as 2048 words by 8 bits. It has a maximum access time of 450 ns to permit use with no wait states in an 8085A CPU.

The I/O portion consists of 2 general purpose I/O ports. Each I/O port has 8 port lines, and each I/O port line is individually programmable as input or output.

The 8755A-2 is a high speed selected version of the 8755A compatible with the 5 MHz 8085A-2 and the 5 MHz iAPX 88 microprocessor.

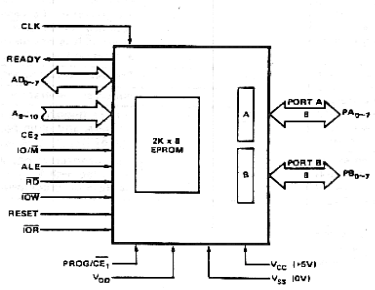

Figure 1. Block Diagram

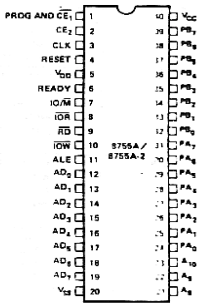

Figure 2. Pin Configuration

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INTEL CORPORATION, 1980

Table 1. Pin Description

Symbol	Type	Name and Function
ALE	I	**Address Latch Enable:** When Address Latch Enable goes *high*, AD_{0-7}, IO/M, A_{8-10}, CE_2, and CE_1 enter the address latches. The signals (AD, IO/M AD_{8-10}, CE_2, CE_1) are latched in at the trailing edge of ALE.
AD_{0-7}	I	**Bidirectional Address/Data Bus:** The lower 8-bits of the PROM or I/O address are applied to the bus lines when ALE is high.
		During an I/O cycle, Port A or B is selected based on the latched value of AD_0. IF RD or IOR is low when the latched Chip Enables are active, the output buffers present data on the bus.
A_{8-10}	I	**Address Bus:** These are the high order bits of the PROM address. They do not affect I/O operations.
PROG/CE_1 CE_2	I	**Chip Enable Inputs:** CE_1 is active low and CE_2 is active high. The 8755A can be accessed only when *both* Chip Enables are active at the time the ALE signal latches them up. If either Chip Enable input is not active, the AD_{0-7} and READY outputs will be in a high impedance state. CE_1 is also used as a programming pin. (See section on programming.)
IO/M	I	**I/O Memory:** If the latched IO/M is high when RD is low, the output data comes from an I/O port. If it is low the output data comes from the PROM.
RD	I	**Read:** If the latched Chip Enables are active when RD goes low, the AD_{0-7} output buffers are enabled and output either the selected PROM location or I/O port. When both RD and IOR are high, the AD_{0-7} output buffers are 3-stated.
IOW	I	**I/O Write:** If the latched Chip Enables are active, a low on IOW causes the output port pointed to by the latched value of AD_0 to be written with the data on AD_{0-7}. The state of IO/M is ignored.
CLK	I	**Clock:** The CLK is used to force the READY into its high impedance state after it has been forced low by CE_1 low, CE_2 high, and ALE high.

Symbol	Type	Name and Function
READY	O	**Ready** is a 3-state output controlled by CE_1, CE_2, ALE and CLK. READY is forced low when the Chip Enables are active during the time ALE is high, and remains low until the rising edge of the next CLK. (See Figure 6c.)
PA_{0-7}	I/O	**Port A:** These are general purpose I/O pins. Their input/output direction is determined by the contents of Data Direction Register (DDR). Port A is selected for write operations when the Chip Enables are active and IOW is low and a 0 was previously latched from AD_0, AD_1.
		Read Operation is selected by either IOR low and active Chip Enables and AD_0 and AD_1 low, *or* IO/M high, RD low, active Chip Enables, and AD_0 and AD_1 low.
PB_{0-7}	I/O	**Port B:** This general purpose I/O port is identical to Port A except that it is selected by a 1 latched from AD_0 and a 0 from AD_1.
RESET	I	**Reset:** In normal operation, an input high on RESET causes all pins in Ports A and B to assume input mode (clear DDR register).
IOR	I	**I/O Read:** When the Chip Enables are active, a low on IOR will output the selected I/O port onto the AD bus. IOR low performs the same function as the combination of IO/M high and RD low. When IOR is not used in a system, IOR should be tied to V_{CC} ("1").
V_{CC}		**Power:** -5 volt supply.
V_{SS}		**Ground:** Reference.
V_{DD}		**Power Supply:** V_{DD} is a programming voltage, and must be tied to V_{CC} when the 8755A is being read.
		For programming, a high voltage is supplied with V_{DD} = 25V, typical. (See section on programming.)

FUNCTIONAL DESCRIPTION

PROM Section

The 8755A contains an 8-bit address latch which allows it to interface directly to MCS-48. MCS-85 and iAPX 88/10 Microcomputers without additional hardware.

The PROM section of the chip is addressed by the 11-bit address and the Chip Enables. The address, CE, and CE_2 are latched into the address latches on the failing edge of ALE. If the latched Chip Enables are active and IO/M is low when RD goes low, the contents of the PROM location addressed by the latched address are put out on the $AD_{0\text{-}7}$ lines (provided that V_{DD} is tied to V_{CC}.)

I/O Section

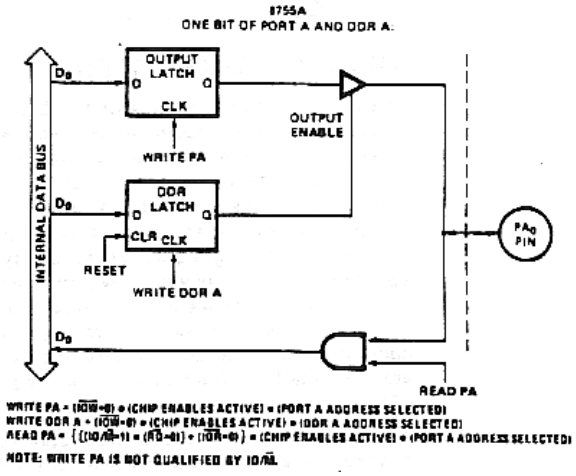
The I/O section of the chip is addressed by the latched value of $AD_{0\text{-}1}$. Two 8-bit Data Direction Registers (DDR) in 8755A determine the input/output status of each pin in the corresponding ports. A "O" in a particular bit position of a DDR signifies that the corresponding I/O port bit is in the input mode. A "1" in a particular bit position signifies that the corresponding I/O port bit is in the output mode. In this manner the I/O ports of the 8755A are bit-by-bit programmable as inputs or outputs. The table summarizes port and DDR designation. DDR's cannot be read.

AD_1	AD_0	Selection
0	0	Port A
0	1	Port B
1	0	Port A Data Direction Register (DDR A)
1	1	Port B Data Direction Register (DDR B)

When IOW goes low and the Chip Enables are active, the data on the $AD_{0\text{-}7}$ is written into I/O port selected by the latched value of $AD_{0\text{-}1}$. During this operation all I/O bits of the selected port are affected, regardless of ~~th~~eir I/O mode and the state of IO/M. The actual output ~~level~~ does not change until IOW returns high. (glitch free output)

A port can be read o<u>ut</u> when the latched C~~hip~~ Enables ~~are a~~ctive and either RD goes low with IO/M high, or IOR goes low. Both input and output mode bits of a selected port will appear on lines $AD_{0\text{-}7}$.

To clarify the function of the I/O Ports and Data Direction Registers, the following diagram shows the configuration of one bit of PORT A and DDR A. The same logic applies to PORT B and DDR B.


8755A
ONE BIT OF PORT A AND DDR A.
OUTPUT LATCH
CLK
WRITE PA
OUTPUT ENABLE
INTERNAL DATA BUS
DDR LATCH
CLR
RESET
WRITE DDR A
PA0 PIN
READ PA
WRITE PA = (IOW=0) • (CHIP ENABLES ACTIVE) • (PORT A ADDRESS SELECTED)
WRITE DDR A = (IOW=0) • (CHIP ENABLES ACTIVE) • (DDR A ADDRESS SELECTED)
READ PA = {(IO/M=1) + (RD=0)} • (IOR=0)} • (CHIP ENABLES ACTIVE) • (PORT A ADDRESS SELECTED)
NOTE: WRITE PA IS NOT QUALIFIED BY IO/M

Note that hardware RESET or writing a zero to the DDR latch will cause the output latch's output buffer to be disabled, preventing the data in the Output Latch from being passed through to the pin. This is equivalent to putting the port in the input mode. Note also that the data can be written to the Output Latch even though the Output Buffer has been disabled. This enables a port to be initialized with a value prior to enabling the output.

The diagram also shows that the contents of PORT A and PORT B can be read even when the ports are configured as outputs.

TABLE 1. 8755A PROGRAMMING MODULE CROSS REFERENCE

MODULE NAME	USE WITH
UPP 955	UPP(4)
UPP UP2(2)	UPP 855
PROMPT 975	PROMPT 80/85(3)
PROMPT 475	PROMPT 48(1)

NOTES:
1. Described on p. 13-34 of 1978 Data Catalog.
2. Special adaptor socket.
3. Described on p. 13-39 of 1978 Data Catalog.
4. Described on p. 13-71 of 1978 Data Catalog.

ERASURE CHARACTERISTICS

The erasure characteristics of the 8755A are such that erasure begins to occur when exposed to light with wavelengths shorter than approximately 4000 Angstroms (A). It should be noted that sunlight and certain types of fluorescent lamps have wavelengths in the 3000-4000A range. Data show that constant exposure to room level fluorescent lighting could erase the typical 8755A in approximately 3 years while it would take approximately 1 week to cause erasure when exposed to direct sunlight. If the 8755A is to be exposed to these types of lighting conditions for extended periods of time, opaque labels are available from intel which should be placed over the 8755 window to prevent unintentional erasure.

The recommended erasure procedure for the 8755A is exposure to shortwave ultraviolet light which has a wavelength of 2537 Angstroms (A). The integrated dose i.e., UV intensity X exposure time for erasure should be a minimum of 15W-sec/cm%r2%r. The erasure time with this dosage is approximately 15 to 20 minutes using an ultraviolet lamp with a 12000µW/cm%r2%r power rating. The 8755A should be placed within one inch from the lamp tubes during erasure. Some lamps have a filter on their tubes and this filter should be removed before erasure.

PROGRAMMING

Initially, and after each erasure, all bits of the EPROM portions of the 8755A are in the "1" state. Information is introduced by selectively programming "0" into the desired bit locations. A programmed "0" can only be changed to a "1" by UV erasure.

The 8755A can be programmed on the Intel (R) Universal PROM Programmer (UPP) and the PROMPT™ 80/85 and PROMPT-48™ design aids. The appropriate programming modules and adapters for use in programming both 8755A's and 8755's are shown in Table 1.

The program mode itself consists of programming a single address at a time, giving a single 50 msec pulse for every address. Generally, it is a desirable to have a verify cycle after a program cycle for the same address as shown in the attached timing diagram. In the verify cycle (i.e., normal memory read cycle) 'VDD' should be at +5V.

Preliminary timing diagrams and parameter values pertaining to the 8755A programming operation are contained in Figure 7.

SYSTEM APPLICATIONS

System Interface with 8085A and IAPX 88

A system using the 8755A can use either one of the two I/O interface techniques:

- Standard I/O
- Memory Mapped I/O

If a standard I/O technique is used, the system can use the feature of both CE_2 and CE_1. By using a combination of unused address lines A_{11-15} and the Chip Enable Inputs, the 8085A system can use up to 5 each 8755A's without requiring a CE decoder. See Figure 4a and 4b.

If a memory mapped I/O approach is used the 8755A will be selected by the combination of both the Chip Enables and IO/M using AD_{8-15} address lines. See Figure 3.

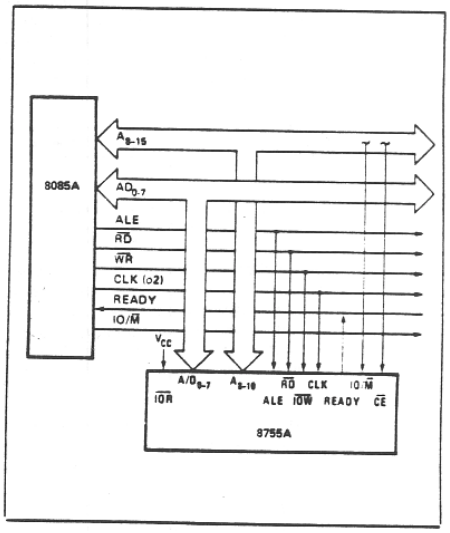


Figure 3. 8755A in 8085A System (Memory-Mapped I/O)

A.C. CHARACTERISTICS (T_A = 0°C to 70° V_{CC} = 5V ± 5%; V_{CC} = V_{DD} = 5V ± 10% for 8755A-2)

Symbol	Parameter	8755A		8755A-2 (Preliminary)		Units
		Min.	Max.	Min.	Max.	
t_{CYC}	Clock Cycle Time	320		200		ns
T_1	CLK Pulse Width	80		40		ns
T_2	CLK Pulse Width	120		70		ns
t_f, t_r	CLK Rise and Fall Time		30		30	ns
t_{AL}	Address to Latch Set Up Time	50		30		ns
t_{LA}	Address Hold Time after Latch	80		45		ns
t_{LC}	Latch to READ/WRITE Control	100		40		ns
t_{RD}	Valid Data Out Delay from READ Control*		170		140	ns
t_{AD}	Address Stable to Data Out Valid**		450		300	ns
t_{LL}	Latch Enable Width	100		70		ns
t_{RDF}	Data Bus Float after READ	0	100	0	85	ns
t_{CL}	READ/WRITE Control to Latch Enable	20		10		ns
t_{CC}	READ/WRITE Control Width	250		200		ns
t_{DW}	Data In to Write Set Up Time	150		150		ns
t_{WD}	Data In Hold Time After WRITE	30		10		ns
t_{WP}	WRITE to Port Output		400		300	ns
t_{PR}	Port Input Set Up Time	50		50		ns
t_{RP}	Port Input Hold Time to Control	50		50		ns
t_{RYH}	READY HOLD Time to Control	0	160	0	160	ns
t_{ARY}	ADDRESS (CE) to READY		160		160	ns
t_{RV}	Recovery Time Between Controls	300		200		ns
t_{RDE}	READ Control to Data Bus Enable	10		10		ns

NOTE:

C_{LOAD} = 150$_{PF}$

*Or T_{AD} - (T_{AL} + T_{LC}) whichever is greater.

**Defines ALE to Data Out Valid in conjunction with T_{AL}

A.C. CHARACTERISTICS - PROGRAMMING (T_A = 0°C to 70°, V_{CC} = 5V ± 5%, V_{SS} = 0V, V_{DD} = 25V ± 1V; V_{CC} = V_{DD} = 5V = 10% for 8755A-2)

Symbol	Parameter	Min.	Typ.	Max.	Unit
t_{PS}	Data Setup Time	10			ns
t_{PD}	Data Hold Time	0			ns
t_S	Prog Pulse Setup Time	2			µs
t_H	Prog Pulse Hold Time	2			µs
t_{PR}	Prog Pulse Rise Time	0.01	2		µs
t_{PF}	Prog Pulse Fall Time	0.01	2		µs
t_{PRG}	Prog Pulse Width	45	50		msec

Jameco Part number 53090

ABSOLUTE MAXIMUM RATINGS*

Temperature Under Bias	0°C to -70°C
Storage Temperature	-65°C to -150°C
Voltage on Any Pin With Respect to Ground	-0.5V to -7V
Power Dissipation	1.5W

** NOTICE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.*

D.C. CHARACTERISTICS (T_A = 0°C to 70°, V_{CC} = V_{DD} = 5V = 5%; V_{CC} = V_{DD} = 5V ±10% for 8755A-2)

SYMBOL	PARAMETER	MIN.	MAX.	UNITS	TEST CONDITIONS
V_{IL}	Input Low Voltage	-0.5	0.8	V	V_{CC} = 5.0V
V_{IH}	Input High Voltage	2.0	V_{CC}+0.5	V	V_{CC} = 5.0V
V_{OL}	Output Low Voltage		0.45	V	I_{OL} = 2mA
V_{OH}	Output High Voltage	2.4		V	I_{OH} = -400µA
I_{IL}	Input Leakage		10	µA	$V_{SS} \leq V_{IN} \leq V_{CC}$
I_{LO}	Output Leakage Current		±10	µA	0.45V ± V_{OUT} ± V_{CC}
I_{CC}	V_{CC} Supply Current		180	mA	
I_{DD}	V_{DD} Supply Current		30	mA	V_{DD} = V_{CC}
C_{IN}	Capacitance of Input Buffer		10	pF	f_C = 1µHz
$C_{I/O}$	Capacitance of I/O Buffer		15	pF	f_C = 1µHz

D.C. CHARACTERISTICS--PROGRAMMING (T_A = 0°C to 70°, V_{CC} = 5V = 5% V_{ss} = 0V. V_{DD} = 25V = 1V: V_{CC} = V_{DD} = 5V ± 10% for 8755A-2)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{DD}	Programming Voltage (during Write to EPROM)	24	25	26	V
I_{DD}	Prog Supply Current		15	30	mA